NSN 5961-00-883-6992

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.328 inches

Overall Diameter:

0.750 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 120.0 breakdown voltage, collector to emitter, sustained and 140.0 collector to

emitter voltage, dc with specified circuit between base and emitter and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

120.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Test Data Document:

98230-ono96882 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

- 1 case and 2 pin Shelf Life: N/a Unit Of Measure: --Demilitarization: No Fiig:
- A110a0